Low-Voltage 1.8/2.5/3.3V 16-Bit Buffer

With 3.6V–Tolerant Inputs and Outputs (3–State, Inverting)

The NL74VCXH16240 is an advanced performance, inverting 16–bit buffer. It is designed for very high–speed, very low–power operation in 1.8V, 2.5V or 3.3V systems.

When operating at 2.5V (or 1.8V) the part is designed to tolerate voltages it may encounter on either inputs or outputs when interfacing to 3.3V busses. It is guaranteed to be over-voltage tolerant to 3.6V.

The NL74VCXH16240 is nibble controlled with each nibble functioning identically, but independently. The control pins may be tied together to obtain full 16–bit operation. The 3–state outputs are controlled by an Output Enable (\overline{OEn}) input for each nibble. When \overline{OEn} is LOW, the outputs are on. When \overline{OEn} is HIGH, the outputs are in the high impedance state. The data inputs include active bushold circuitry, eliminating the need for external pull–up resistors to hold unused or floating inputs at a valid logic state.

- Designed for Low Voltage Operation: $V_{CC} = 1.65 3.6V$
- 3.6V Tolerant Inputs and Outputs
- High Speed Operation: 2.5ns max for 3.0 to 3.6V 3.0ns max for 2.3 to 2.7V

6.0ns max for 1.65 to 1.95V

• Static Drive: ±24mA Drive at 3.0V ±18mA Drive at 2.3V ±6mA Drive at 1.65V

- Supports Live Insertion and Withdrawal
- Includes Active Bushold to Hold Unused or Floating Inputs at a Valid Logic State
- IOFF Specification Guarantees High Impedance When $V_{CC} = 0V^+$
- Near Zero Static Supply Current in All Three Logic States (20µA) Substantially Reduces System Power Requirements
- Latchup Performance Exceeds ±300mA @ 125°C
- ESD Performance: Human Body Model >2000V; Machine Model >200V

†NOTE: To ensure the outputs activate in the 3–state condition, the output enable pins should be connected to V_{CC} through a pull–up resistor. The value of the resistor is determined by the current sinking capability of the output connected to the $\overline{\text{OE}}$ pin.



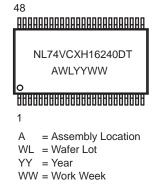
ON Semiconductor

http://onsemi.com



TSSOP-48 DT SUFFIX CASE 1201

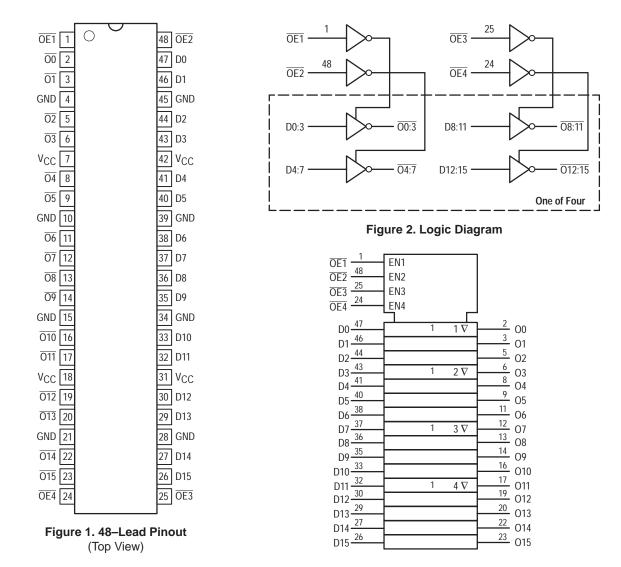
MARKING DIAGRAM



PIN NAMES			
Pins	Function		
OEn D0–D15 O0–O15	Output Enable Inputs Inputs Outputs		

ORDERING INFORMATION

Device	Package	Shipping
NL74VCXH16240DT	TSSOP	39 / Rail
NL74VCXH16240DTR	TSSOP	2500 / Reel



OE1	D0:3	00:3	OE2	D4:7	04:7	OE3	D8:11	08:11	OE4	D12:15	012:15
L	L	Н	L	L	Н	L	L	Н	L	L	Н
L	Н	L	L	Н	L	L	Н	L	L	Н	L
Н	Х	Z	Н	Х	Z	Н	Х	Z	Н	Х	Z

H = High Voltage Level; L = Low Voltage Level; Z = High Impedance State; X = High or Low Voltage Level and Transitions Are Acceptable, for I_{CC} reasons, DO NOT FLOAT Inputs

ABSOLUTE MAXIMUM RATINGS*

Symbol	Parameter	Value	Condition	Unit
V _{CC}	DC Supply Voltage	-0.5 to +4.6		V
VI	DC Input Voltage	$-0.5 \le V_I \le +4.6$		V
VO	DC Output Voltage	$-0.5 \le V_O \le +4.6$	Output in 3–State	V
		$-0.5 \le V_O \le V_{CC} + 0.5$	Note 1.; Outputs Active	V
lικ	DC Input Diode Current	-50	V _I < GND	mA
lok	DC Output Diode Current	-50	V _O < GND	mA
		+50	AO > ACC	mA
IO	DC Output Source/Sink Current	±50		mA
ICC	DC Supply Current Per Supply Pin	±100		mA
I _{GND}	DC Ground Current Per Ground Pin	±100		mA
T _{STG}	Storage Temperature Range	-65 to +150		°C

* Absolute maximum continuous ratings are those values beyond which damage to the device may occur. Exposure to these conditions or conditions beyond those indicated may adversely affect device reliability. Functional operation under absolute-maximum-rated conditions is not implied.

1. IO absolute maximum rating must be observed.

RECOMMENDED OPERATING CONDITIONS

Symbol	Parameter		Min	Тур	Мах	Unit
VCC	Supply Voltage	Operating Data Retention Only	1.65 1.2	3.3 3.3	3.6 3.6	V
VI	Input Voltage		-0.3		3.6	V
VO	Output Voltage	(Active State) (3–State)	0 0		V _{CC} 3.6	V
ЮН	HIGH Level Output Current, $V_{CC} = 3.0V - 3.6V$				-24	mA
IOL	LOW Level Output Current, V _{CC} = 3.0V – 3.6V				24	mA
IОН	HIGH Level Output Current, $V_{CC} = 2.3V - 2.7V$				-18	mA
IOL	LOW Level Output Current, $V_{CC} = 2.3V - 2.7V$				18	mA
ЮН	HIGH Level Output Current, V _{CC} = 1.65 – 1.95V				-6	mA
I _{OL}	LOW Level Output Current, V _{CC} = 1.65 – 1.95V				6	mA
Т _А	Operating Free–Air Temperature		-40		+85	°C
$\Delta t / \Delta V$	Input Transition Rise or Fall Rate, VIN from 0.8V to 2	.0V, V _{CC} = 3.0V	0		10	ns/V

DC ELECTRICAL CHARACTERISTICS

			T _A = −40°		
Symbol	Characteristic	Condition	Min	Max	Unit
VIH	HIGH Level Input Voltage (Note 2.)	1.65V ≤ V _{CC} < 2.3V	0.65 x V _{CC}		V
		$2.3V \le V_{CC} \le 2.7V$	1.6		
		2.7V < V _{CC} ≤ 3.6V	2.0		
VIL	LOW Level Input Voltage (Note 2.)	1.65V ≤ V _{CC} < 2.3V		0.35 x V _{CC}	V
		$2.3V \le V_{CC} \le 2.7V$		0.7	
		2.7V < V _{CC} ≤ 3.6V		0.8	
VOH	HIGH Level Output Voltage	$1.65V \le V_{CC} \le 3.6V; I_{OH} = -100\mu A$	V _{CC} - 0.2		V
-		V _{CC} = 1.65V; I _{OH} = -6mA	1.25		
		V _{CC} = 2.3V; I _{OH} = -6mA	2.0		
		V _{CC} = 2.3V; I _{OH} = -12mA	1.8		
		V _{CC} = 2.3V; I _{OH} = -18mA	1.7		
		V _{CC} = 2.7V; I _{OH} = -12mA	2.2		
		V _{CC} = 3.0V; I _{OH} = -18mA	2.4		
		V _{CC} = 3.0V; I _{OH} = -24mA	2.2		
VOL	LOW Level Output Voltage	$1.65V \le V_{CC} \le 3.6V; I_{OL} = 100\mu A$		0.2	V
		V _{CC} = 1.65V; I _{OL} = 6mA		0.3	
		V _{CC} = 2.3V; I _{OL} = 12mA		0.4	
		V _{CC} = 2.3V; I _{OL} = 18mA		0.6	
		V _{CC} = 2.7V; I _{OL} = 12mA		0.4	
		V _{CC} = 3.0V; I _{OL} = 18mA		0.4	
		$V_{CC} = 3.0V; I_{OL} = 24mA$		0.55	
lı	Input Leakage Current	$1.65 \text{V} \le \text{V}_{CC} \le 3.6 \text{V}; \ 0 \text{V} \le \text{V}_{I} \le 3.6 \text{V}$		±5.0	μA
II(HOLD)	Minimum Bushold Input Current	V _{CC} = 3.0V, V _{IN} = 0.8V	75		μA
		V _{CC} = 3.0V, V _{IN} = 2.0V	-75		1
		V _{CC} = 2.3V, V _{IN} = 0.7V	45		
		V _{CC} = 2.3V, V _{IN} = 1.6V	-45		
		V _{CC} = 1.65V, V _{IN} = 0.57V	25		
		V _{CC} = 1.65V, V _{IN} = 1.07V	-25		
II (OD)	Minimum Bushold Over–Drive	V _{CC} = 3.6V, (Note 3.)	450		μA
()	Current Needed to Change State	V _{CC} = 3.6V, (Note 4.)	-450		
		V _{CC} = 2.7V, (Note 3.)	300		
		V _{CC} = 2.7V, (Note 4.)	-300		
		V _{CC} = 1.95V, (Note 3.)	200		
		V _{CC} = 1.95V, (Note 4.)	-200		
IOZ	3-State Output Current	$1.65V \le V_{CC} \le 3.6V; \ 0V \le V_O \le 3.6V;$ $V_I = V_{IH} \text{ or } V_{IL}$		±10	μΑ
IOFF	Power–Off Leakage Current	$V_{CC} = 0V; V_I \text{ or } V_O = 3.6V$		10	μA
ICC	Quiescent Supply Current (Note 5.)	$1.65V \le V_{CC} \le 3.6V$; V _I = GND or V _{CC}		20	μΑ
		$1.65V \le V_{CC} \le 3.6V; 3.6V \le V_{I}, V_{O} \le 3.6V$		±20	μΑ
ΔlCC	Increase in I _{CC} per Input	$2.7V < V_{CC} \le 3.6V; V_{IH} = V_{CC} - 0.6V$	+	750	μΑ

These values of V_I are used to test DC electrical characteristics only.
An external driver must source at least the specified current to switch from LOW-to-HIGH
An external driver must source at least the specified current to switch from HIGH-to-LOW
Outputs disabled or 3-state only.

AC CHARACTERISTICS (Note 6.; $t_R = t_F = 2.0ns$; $C_L = 30pF$; $R_L = 500\Omega$)

					Liı	nits			
					T _A = −40°	C to +85°C			
			V _{CC} = 3.0)V to 3.6V	V _{CC} = 2.3	3V to 2.7V	V _{CC} = 1.6	5 to 1.95V	1
Symbol	Parameter	Waveform	Min	Max	Min	Max	Min	Мах	Unit
^t PLH ^t PHL	Propagation Delay Input to Output	1	0.8 0.8	2.5 2.5	1.0 1.0	3.0 3.0	1.5 1.5	6.0 6.0	ns
^t PZH ^t PZL	Output Enable Time to High and Low Level	2	0.8 0.8	3.5 3.5	1.0 1.0	4.1 4.1	1.5 1.5	8.2 8.2	ns
^t PHZ ^t PLZ	Output Disable Time From High and Low Level	2	0.8 0.8	3.5 3.5	1.0 1.0	3.8 3.8	1.5 1.5	7.8 7.8	ns
^t OSHL ^t OSLH	Output-to-Output Skew (Note 7.)			0.5 0.5		0.5 0.5		0.75 0.75	ns

6. For $C_L = 50 pF$, add approximately 300ps to the AC maximum specification.

 Skew is defined as the absolute value of the difference between the actual propagation delay for any two separate outputs of the same device. The specification applies to any outputs switching in the same direction, either HIGH–to–LOW (t_{OSHL}) or LOW–to–HIGH (t_{OSLH}); parameter guaranteed by design.

DYNAMIC SWITCHING CHARACTERISTICS

			T _A = +25°C	
Symbol	Characteristic	Condition	Тур	Unit
VOLP	Dynamic LOW Peak Voltage	$V_{CC} = 1.8V, C_L = 30pF, V_{IH} = V_{CC}, V_{IL} = 0V$	0.25	V
	(Note 8.)	V_{CC} = 2.5V, C_L = 30pF, V_{IH} = V_{CC} , V_{IL} = 0V	0.6	
		V_{CC} = 3.3V, C_L = 30pF, V_{IH} = V_{CC} , V_{IL} = 0V	0.8	
VOLV	Dynamic LOW Valley Voltage	V_{CC} = 1.8V, C_L = 30pF, V_{IH} = V_{CC} , V_{IL} = 0V	-0.25	V
	(Note 8.)	V_{CC} = 2.5V, C_L = 30pF, V_{IH} = V_{CC} , V_{IL} = 0V	-0.6	
		V_{CC} = 3.3V, C_{L} = 30pF, V_{IH} = V_{CC} , V_{IL} = 0V	-0.8	
VOHV	Dynamic HIGH Valley Voltage	V_{CC} = 1.8V, C_L = 30pF, V_{IH} = V_{CC} , V_{IL} = 0V	1.5	V
	(Note 9.)	V_{CC} = 2.5V, C_L = 30pF, V_{IH} = V_{CC} , V_{IL} = 0V	1.9]
		V_{CC} = 3.3V, C_{L} = 30pF, V_{IH} = V_{CC} , V_{IL} = 0V	2.2	

8. Number of outputs defined as "n". Measured with "n-1" outputs switching from HIGH-to-LOW or LOW-to-HIGH. The remaining output is measured in the LOW state.

9. Number of outputs defined as "n". Measured with "n–1" outputs switching from HIGH-to-LOW or LOW-to-HIGH. The remaining output is measured in the HIGH state.

CAPACITIVE CHARACTERISTICS

Symbol	Parameter	Condition	Typical	Unit
C _{IN}	Input Capacitance	Note 10.	6	pF
C _{OUT}	Output Capacitance	Note 10.	7	pF
C _{PD}	Power Dissipation Capacitance	Note 10., 10MHz	20	pF

10. V_{CC} = 1.8, 2.5 or 3.3V; V_I = 0V or V_{CC}.

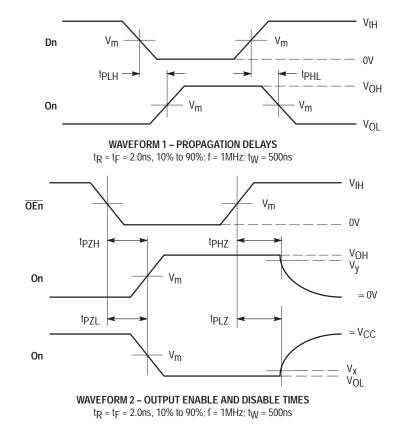
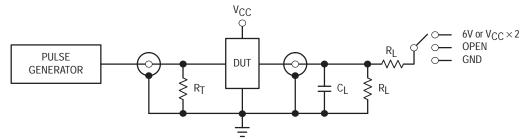


Figure 3. AC Waveforms

	Vcc					
Symbol	3.3V ±0.3V	2.5V ±0.2V	1.8V ±0.15V			
VIH	2.7V	Vcc	VCC			
Vm	1.5V	V _{CC} /2	V _{CC} /2			
V _X	V _{OL} + 0.3V	V _{OL} + 0.15V	V _{OL} + 0.15V			
Vy	V _{OH} – 0.3V	V _{OH} – 0.15V	V _{OH} – 0.15V			



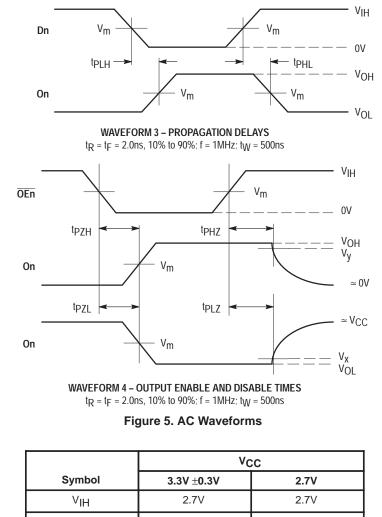
TEST	SWITCH		
^t PLH ^{, t} PHL	Open		
^t PZL [,] ^t PLZ	6V at V _{CC} = 3.3 ±0.3V; V _{CC} × 2 at V _{CC} = 2.5 ±0.2V; 1.8 ±0.15V		
tрун, tрну	GND		

C_L = 30pF or equivalent (Includes jig and probe capacitance)

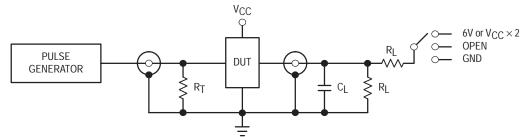
 $R_{L} = 500\Omega$ or equivalent

 $R_T^- = Z_{OUT}$ of pulse generator (typically 50 Ω)

Figure 4. Test Circuit



	Vcc				
Symbol	3.3V ±0.3V	2.7V			
VIH	2.7V	2.7V			
V _m	1.5V	1.5V			
V _X	V _{OL} + 0.3V	V _{OL} + 0.3V			
Vy	V _{OH} – 0.3V	V _{OH} – 0.3V			



TEST	SWITCH
^t PLH, ^t PHL	Open
^t PZL ^{, t} PLZ	6V at V _{CC} = 3.3 ±0.3V; V _{CC} × 2 at V _{CC} = 2.5 ±0.2V; 1.8 ±0.15V
^t PZH ^{, t} PHZ	GND

 $C_L = 50 pF$ or equivalent (Includes jig and probe capacitance)

 $R_L = 500\Omega$ or equivalent (included) ig and prod $R_T = Z_{OUT}$ of pulse generator (typically 50 Ω)

Figure 6. Test Circuit

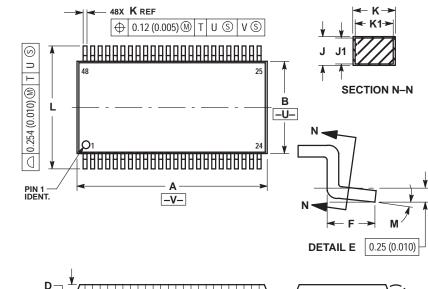
AC CHARACTERISTICS ($t_R = t_F = 2.0ns$; $C_L = 50pF$; $R_L = 500\Omega$)

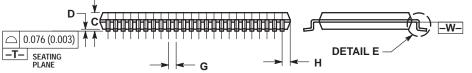
			Limits T _A = -40°C to +85°C				- 1
			V _{CC} = 3.0V to 3.6V		V _{CC} = 2.7V		1
Symbol	Parameter	Waveform	Min	Max	Min	Max	Unit
^t PLH ^t PHL	Propagation Delay Input to Output	3	1.0 1.0	3.9 3.9		5.3 5.3	ns
^t PZH ^t PZL	Output Enable Time to High and Low Level	4	1.0 1.0	5.0 5.0		6.1 6.1	ns
^t PHZ ^t PLZ	Output Disable Time From High and Low Level	4	1.0 1.0	4.4 4.4		4.8 4.8	ns
^t OSHL ^t OSLH	Output–to–Output Skew (Note 11.)			0.5 0.5		0.5 0.5	ns

11. Skew is defined as the absolute value of the difference between the actual propagation delay for any two separate outputs of the same device. The specification applies to any outputs switching in the same direction, either HIGH–to–LOW (tOSHL) or LOW–to–HIGH (tOSLH); parameter guaranteed by design.

PACKAGE DIMENSIONS

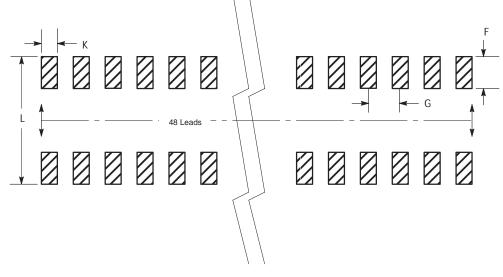
TSSOP **DT SUFFIX** CASE 1201-01 **ISSUE A**



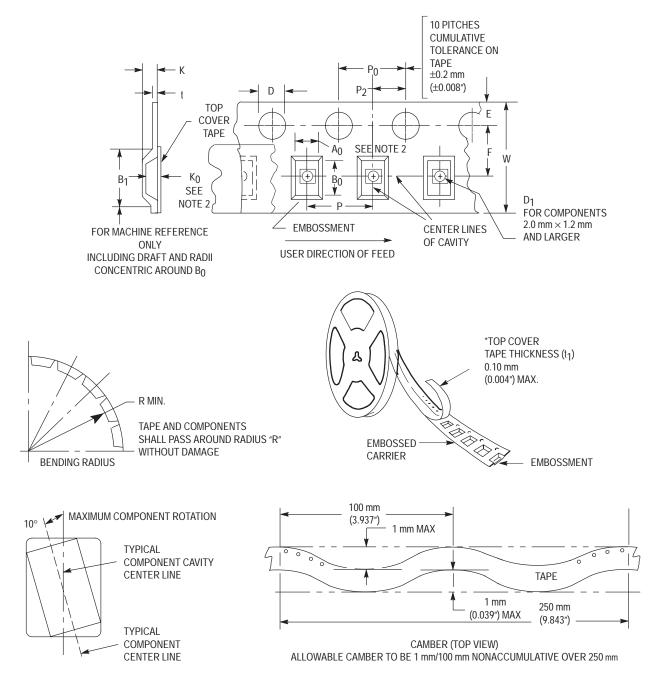


- NOTES: 1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982. 2. CONTROLLING DIMENSION: MILLIMETER. 3. DIMENSIONS A AND B DO NOT INCLUDE MOLD FLASH, PROTRUSIONS OR GATE BURRS. MOLD FLASH OR GATE BURRS SHALL NOT EXCEED 0.15 (# 0004) DED SHE SHALL NOT EXCEED 0.15 (0.006) PER SIDE. 4. DIMENSION K DOES NOT INCLUDE DAMBAR
- PROTRUSION. ALLOWABLE DAMBAR PROTRUSION SHALL BE 0.08 (0.003) TOTAL IN EXCESS OF THE K DIMENSION AT MAXIMUM MATERIAL CONDITION.
- 5. TERMINAL NUMBERS ARE SHOWN FOR
- REFERENCE ONLY. DIMENSIONS A AND B ARE TO BE DETERMINED AT DATUM PLANE -W-. 6.

	MILLIN	IETERS	INCHES		
DIM	MIN	MAX	MIN	MAX	
Α	12.40	12.60	0.488	0.496	
В	6.00	6.20	0.236	0.244	
С		1.10		0.043	
D	0.05	0.15	0.002	0.006	
F	0.50	0.75	0.020	0.030	
G	0.50 BSC		0.0197 BSC		
Н	0.37		0.015		
J	0.09	0.20	0.004	0.008	
J1	0.09	0.16	0.004	0.006	
K	0.17	0.27	0.007	0.011	
K1	0.17	0.23	0.007	0.009	
L	7.95	8.25	0.313	0.325	
Μ	0 °	8 °	0 °	8 °	



Package Footprint





Tape Size	B ₁ Max	D	D ₁	E	F	к	Р	P ₀	P ₂	R	т	w
24mm	20.1mm (0.791″)	1.5 + 0.1mm -0.0 (0.059 +0.004" -0.0)	1.5mm Min (0.060″)	1.75 ±0.1 mm (0.069 ±0.004")	11.5 ±0.10 mm (0.453 ±0.004")	11.9 mm Max (0.468")	16.0 ±0.1 mm (0.63 ±0.004")	4.0 ±0.1 mm (0.157 ±0.004")	2.0 ±0.1 mm (0.079 ±0.004")	30 mm (1.18")	0.6 mm (0.024")	24.3 mm (0.957")

EMBOSSED	CARRIER	DIMENSIONS	(See	Notes	1 and 2)

1. Metric Dimensions Govern–English are in parentheses for reference only.

 A₀, B₀, and K₀ are determined by component size. The clearance between the components and the cavity must be within 0.05 mm min to 0.50 mm max. The component cannot rotate more than 10° within the determined cavity

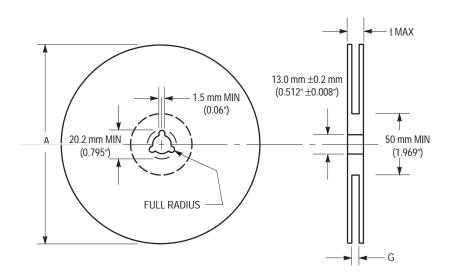
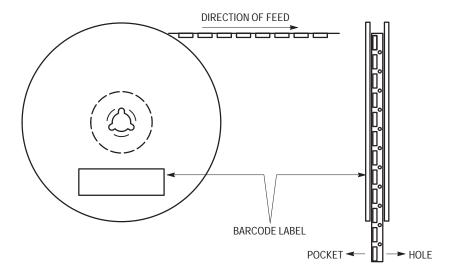


Figure 8. Reel Dimensions

REEL DIMENSIONS

Tape Size	A Max	G	t Max
24 mm	360 mm	24.4 mm + 2.0 mm, -0.0	30.4 mm
	(14.173")	(0.961" + 0.078", -0.00)	(1.197″)





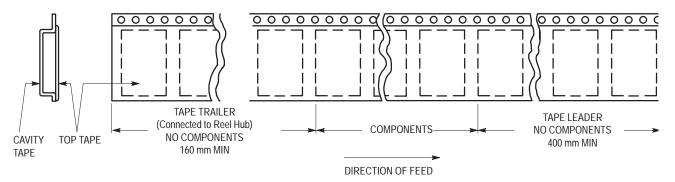


Figure 10. Tape Ends for Finished Goods

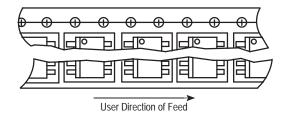


Figure 11. Reel Configuration

ON Semiconductor and without further notice to any products herein. SCILLC makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does SCILLC assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. "Typical" parameters which may be provided in SCILLC data sheets and/or specifications can and do vary in different applications and actual performance may vary over time. All operating parameters, including "Typicals" must be validated for each customer application by customer's technical experts. SCILLC does not convey any license under its patent rights nor the rights of others. SCILLC products are not designed, intended, or authorized for use as components in systems intended for surgical implant into the body, or other applications intended to support or sustain life, or for any other application in which the failure of the SCILLC product could create a situation where personal injury or death may occur. Should Buyer purchase or use SCILLC products for any such unintended or unauthorized application, Buyer shall indemnify and hold SCILLC and its officers, employees, subsidiaries, and distributors harmless against all claims, costs, damages, and expenses, and reasonable attorney fees arising out of, directly or indirectly, any claim of personal injury or death associated with such unintended or unauthorized use, even if such claim alleges that SCILLC was negligent regarding the design or manufacture of the part. SCILLC is an Equal Opportunity/Affirmative Action Employer.

PUBLICATION ORDERING INFORMATION

NORTH AMERICA Literature Fulfillment:

Literature Distribution Center for ON Semiconductor P.O. Box 5163, Denver, Colorado 80217 USA Phone: 303–675–2175 or 800–344–3860 Toll Free USA/Canada Fax: 303–675–2176 or 800–344–3867 Toll Free USA/Canada Email: ONlit@hibbertco.com Fax Response Line: 303–675–2167 or 800–344–3810 Toll Free USA/Canada

N. American Technical Support: 800-282-9855 Toll Free USA/Canada

EUROPE: LDC for ON Semiconductor – European Support German Phone: (+1) 303–308–7140 (M–F 1:00pm to 5:00pm Munich Time)

Email: ONlit-german@hibbertco.com

- French Phone: (+1) 303–308–7141 (M–F 1:00pm to 5:00pm Toulouse Time) Email: ONlit-french@hibbertco.com
- English Phone: (+1) 303–308–7142 (M–F 12:00pm to 5:00pm UK Time) Email: ONlit@hibbertco.com

EUROPEAN TOLL-FREE ACCESS*: 00-800-4422-3781 *Available from Germany, France, Italy, England, Ireland

CENTRAL/SOUTH AMERICA:

Spanish Phone: 303–308–7143 (Mon–Fri 8:00am to 5:00pm MST) Email: ONlit–spanish@hibbertco.com

ASIA/PACIFIC: LDC for ON Semiconductor – Asia Support Phone: 303–675–2121 (Tue–Fri 9:00am to 1:00pm, Hong Kong Time) Toll Free from Hong Kong & Singapore: 001–800–4422–3781 Email: ONlit–asia@hibbertco.com

JAPAN: ON Semiconductor, Japan Customer Focus Center 4–32–1 Nishi–Gotanda, Shinagawa–ku, Tokyo, Japan 141–8549 Phone: 81–3–5740–2745 Email: r14525@onsemi.com

ON Semiconductor Website: http://onsemi.com

For additional information, please contact your local Sales Representative.